NSN 5961-01-158-1053

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View Online at https://aerobasegroup.com/nsn/5961-01-158-1053 **Inclosure Material:** Ceramic **Overall Length:** 0.610 inches **Overall Width:** 0.405 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 50.0 collector-to-emitter, resistance between base and emitter and 3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 20.00 milliamperes collector cutoff current, dc, emitter open **Power Rating Per Characteristic:** 229.0 watts total power dissipation **Transfer Ratio:** 120.0 small-signal short-circuit forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: